

# TX61C series Low Power Voltage Detector

#### **Features**

- Low power consumption
- Low temperature coefficient
- Built-in hysteresis characteristic
- High input voltage (up to 8V)
- Output voltage accuracy:

 $\pm 2\%$ @VDET $\geqslant$ 2.5mV

 $\pm 50 \text{mV@VDET} < 2.5 \text{mV}$ 

SOT23-3 and SOT23 package

#### **Applications**

- Battery checkers
- Level selectors
- Power failure detectors
- Microcomputer reset
- Battery memory backup
- Non-volatile RAM signal storage protectors

#### **General Description**

The TX61C series devices are a set of three terminal low power voltage detectors implemented in CMOS technology. Each voltage detector in the series detects a particular fixed voltage ranging from 0.9V to 5.0V. The voltage detectors consist of a high-precision and low power consumption standard voltage source as well as a comparator,

hysteresis circuit, and an output driver (CMOS inverter or NMOS open drain). CMOS technology ensures low power consumption.

Although designed primarily as fixed voltage detectors, these devices can be used with external components to detect user specified threshold voltages.

#### **Selection Table**

Part No.	Det. Voltage	Hys. Width	Output	Tolerance	Package
TX61CC0902MR	0.9V	4%	CMOS	$\pm 50 \text{mV}$	
TX61CN0902MR	0.9V	4%	NMOS	$\pm 50 \mathrm{mV}$	
TX61CC1002MR	1.0V	4%	CMOS	$\pm 50 \text{mV}$	
TX61CN1002MR	1.0V	4%	NMOS	$\pm 50 \text{mV}$	
•••	•••	•••	•••	•••	
TX61CC2402MR	2.4V	4%	CMOS	$\pm 50 \text{mV}$	SOT23-3
TX61CN2402MR	2.4V	4%	NMOS	$\pm 50 \text{mV}$	SOT23
TX61CC2502MR	2.5V	4%	CMOS	±2%	
TX61CN2502MR	2.5V	4%	NMOS	±2%	
•••	•••	•••		±2%	
TX61CC5002MR	5.0V	4%	CMOS	±2%	
TX61CN5002MR	5.0V	4%	NMOS	±2%	



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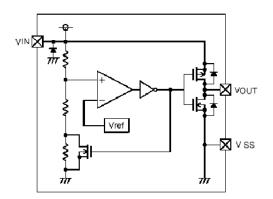
#### **Order Information**

TX61C1234567

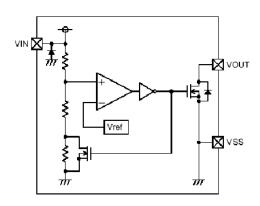
Designator	Symbol	Description	
(1)	С	CMOS output	
(1)	N	NMOS output	
23	VOUT	Output Voltage(0.9~5.0V)	
45	02	Standard	
(e)	M	Package:SOT23-3	
6	N	Package:SOT23	
	R	RoHS / Pb Free	
7	G	Halogen Free	

## **Block Diagram**

#### (1) CMOS Output



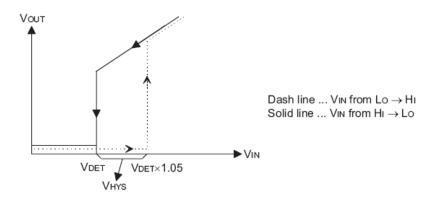
#### (2) N-ch Open Drain Output



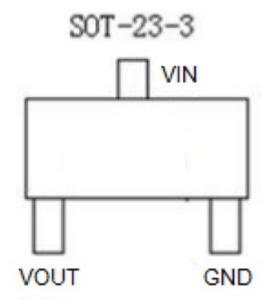
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### **Output Table & Curve**

$V_{DD}$	V <sub>DD</sub> >V <sub>DET</sub> (+)	$V_{DD} \leqslant V_{DET}$ (-)
Vout	Hi-Z	Vss



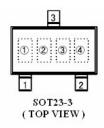
### **Pin Assignment**





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### **Marking Rule**



## ① Represents integer of detect voltage and CMOS Output

MARK	CONFIGURATION	VOLTAGE (V)
Α	CMOS	0.X
В	CMOS	1.X
С	CMOS	2.X
D	CMOS	3.X
E	CMOS	4.X
F	CMOS	5.X
Н	CMOS	6.X

#### N-Channel Open Drain Output

MARK	CONFIGURATION	VOLTAGE (V)
K	N-ch	0.X
L	N-ch	1.X
M	N-ch	2.X
N	N-ch	3.X
P	N-ch	4.X
R	N-ch	5.X
S	N-ch	6.X

#### @Represents decimal number of detect voltage

MARK	VOLTAGE (V)	MARK	VOLTAGE (V)
0	X.0	5	X.5
1	X.1	6	X.6
2	X.2	7	X.7
3	X.3	8	X.8
4	X.4	9	X.9

#### 3 Represents accuracy

MARK	ACCURACY
3	2%
1	1%

(4) Represents production lot number

Based on the internal standard. (G, I, J, O, Q, W excepted)



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#### **Absolute Maximum Ratings**

Supply Voltage .....-0.3V to 10V Storage Temperature .....-50°C to 125°C Operating Temperature ....-40°C to 85°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

#### **Thermal Information**

Symbol	Parameter	Package	Max.	Unit
θ ЈА	Thermal Resistance (Junction to Ambient) (Assume no ambient airflow, no heat sink)	SOT23-3	500	°C/W
P <sub>D</sub>	Power Dissipation	SOT23-3	0.20	W

Note: P<sub>D</sub> is measured at Ta= 25 °C

#### **Electrical Characteristics**

V<sub>DF</sub>=0.8V~5.0V Ta=25°C

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
\/		V	<sub>DF</sub> =0.9V~2.4V	V <sub>DET</sub> -0.05	VDET	V <sub>DET</sub> +0.05	٧
VDET	Detection Voltage	V <sub>DF</sub> =2.5V~5.0V		V <sub>DET</sub> *0.98	$V_{DET}$	V <sub>DET</sub> *1.02	V
V <sub>HYS</sub>	Hysteresis Width	-		0.02*V <sub>DET</sub>	0.05*V <sub>DET</sub>	0.10*V <sub>DET</sub>	٧
		Vin=1.5V Vin=2.0V		-	0.7	2.3	μΑ
				-	0.8	2.7	
$I_{DD}$	Operating Current	Vin=3.0V		-	0.9	3.0	
		Vin=4.0V		-	1.0	3.2	
			Vin=5.0V	-	1.1	3.6	
$V_{DD}$	Operating Voltage	ı	-	0.7	ı	10	>
loL	Output Sink Current	2V	V <sub>OUT</sub> =0.2V	0.5	1	-	mA
$\frac{\Delta V_{\scriptscriptstyle DET}}{V_{\scriptscriptstyle DF}\Delta T_{\scriptscriptstyle a}}$	Temperature Coefficient	-	-25℃ <ta<125℃< td=""><td>-</td><td>±100</td><td>-</td><td>ppm/°C</td></ta<125℃<>	-	±100	-	ppm/°C

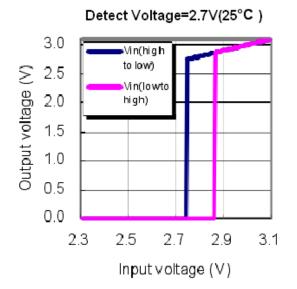


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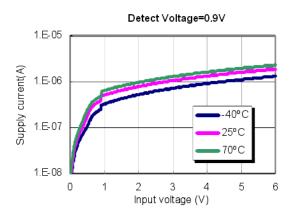
### **Typical Performance Characteristics**

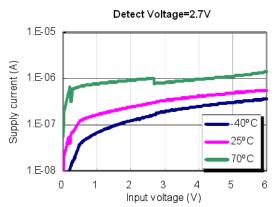
#### (1) Output Voltage vs Input voltage

#### Detect Voltage=0.9V(25°C) Vin(high to 1.4 low) Vin(lowto 1.2 Output voltage (V) high) 1.0 8.0 0.6 0.4 0.2 0.0 0.5 0.7 0.9 1.1 1.3 1.5 Input voltage (V)



#### (2) Supply Current vs. Input Voltage





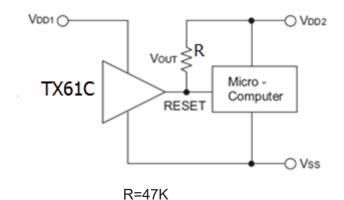


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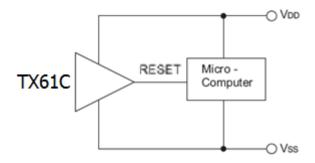
#### **Microcomputer Reset Circuit**

Normally a reset circuit is required to protect the microcomputer system from malfunctions due to power line interruptions. The following examples show how different output configurations perform a reset function in various systems.

NMOS open drain output application for separate power supply



CMOS output application



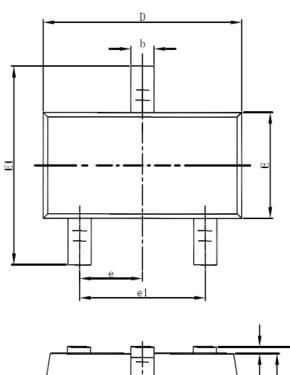


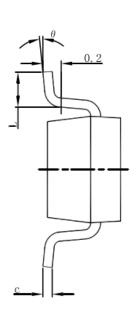
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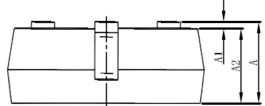
#### http://www.txsemi.com

## **Package Information**

### 3-pin SOT23-3 Outline Dimensions







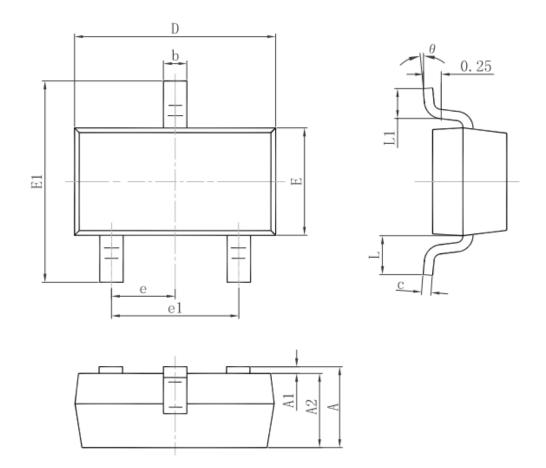
Cumb o l	Dimensions In	n Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950	(BSC)	0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°



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### **3-pin SOT23 Outline Dimensions**



Combal	Dimensions	Dimensions In Millimeters		s In Inches	
Symbol	Min.	Max.	Min.	Max.	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950	TYP.	0.037	TYP.	
e1	1.800	2.000	0.071	0.079	
L	0.550	0.550 REF.		REF.	
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	



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#### 说明书更改说明:

版本	操作者	日期	更改内容	更改来源
1.2	郭玲博	2019-3-28	精度范围以 2.5V 划分, 2.5V 以	测试说明。
			下是±50mV,2.5V 以上是±2%	